

US 20110088783A1

(19) **United States**

(12) **Patent Application Publication**
Park et al.

(10) **Pub. No.: US 2011/0088783 A1**

(43) **Pub. Date: Apr. 21, 2011**

(54) **SOLAR CELL HAVING ORGANIC NANOWIRES**

(30) **Foreign Application Priority Data**

Oct. 15, 2009 (KR) 10-2009-0098412

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Publication Classification

(51) **Int. Cl.**
H01L 31/00 (2006.01)

(52) **U.S. Cl.** **136/263**

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(57) **ABSTRACT**

(21) Appl. No.: **12/656,837**

Example embodiments relate to a solar cell including organic nanowires. The solar cell may include a photoelectric conversion layer formed of a p-type material including an organic material and an n-type material including organic nanowires.

(22) Filed: **Feb. 17, 2010**

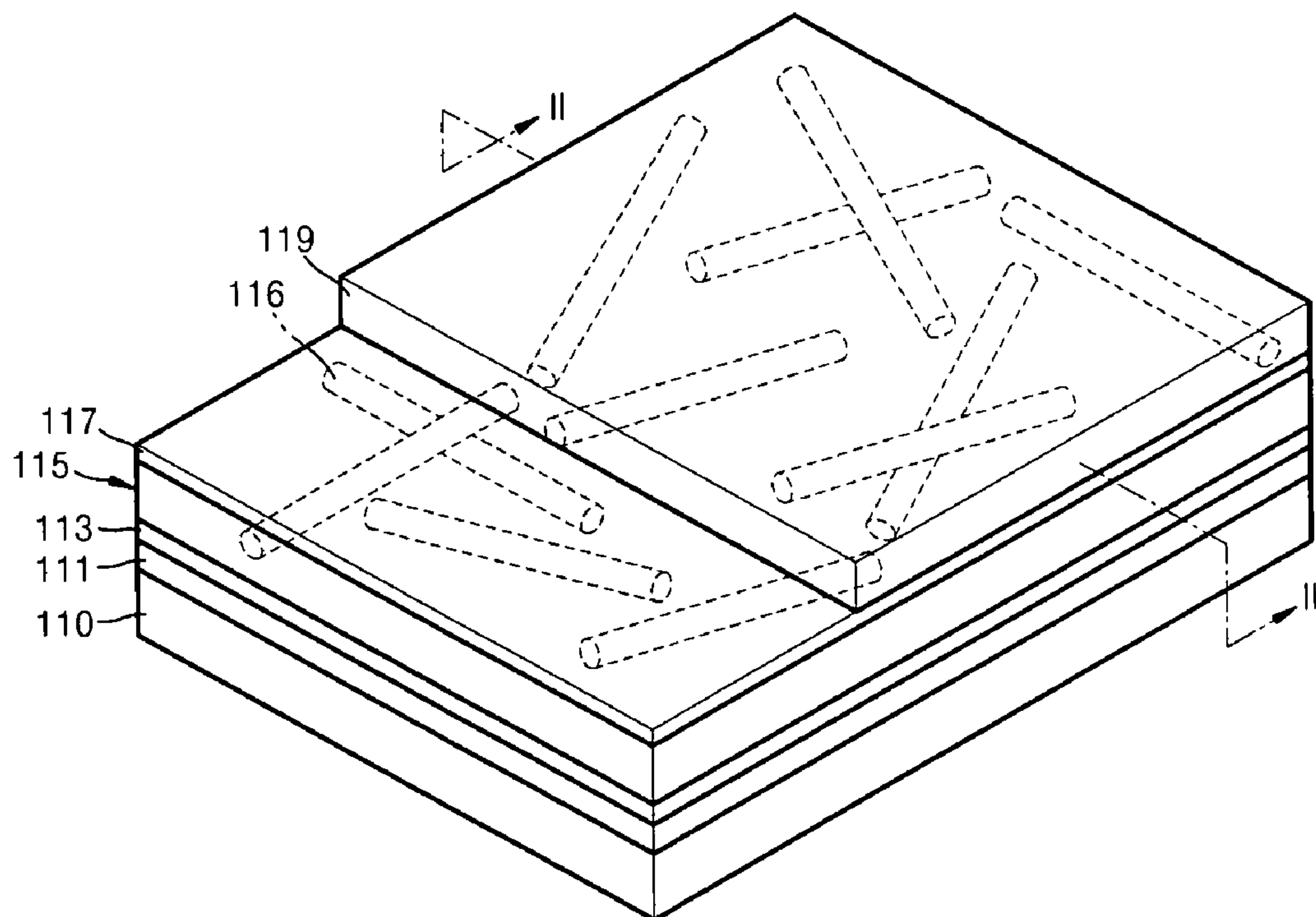


FIG. 1

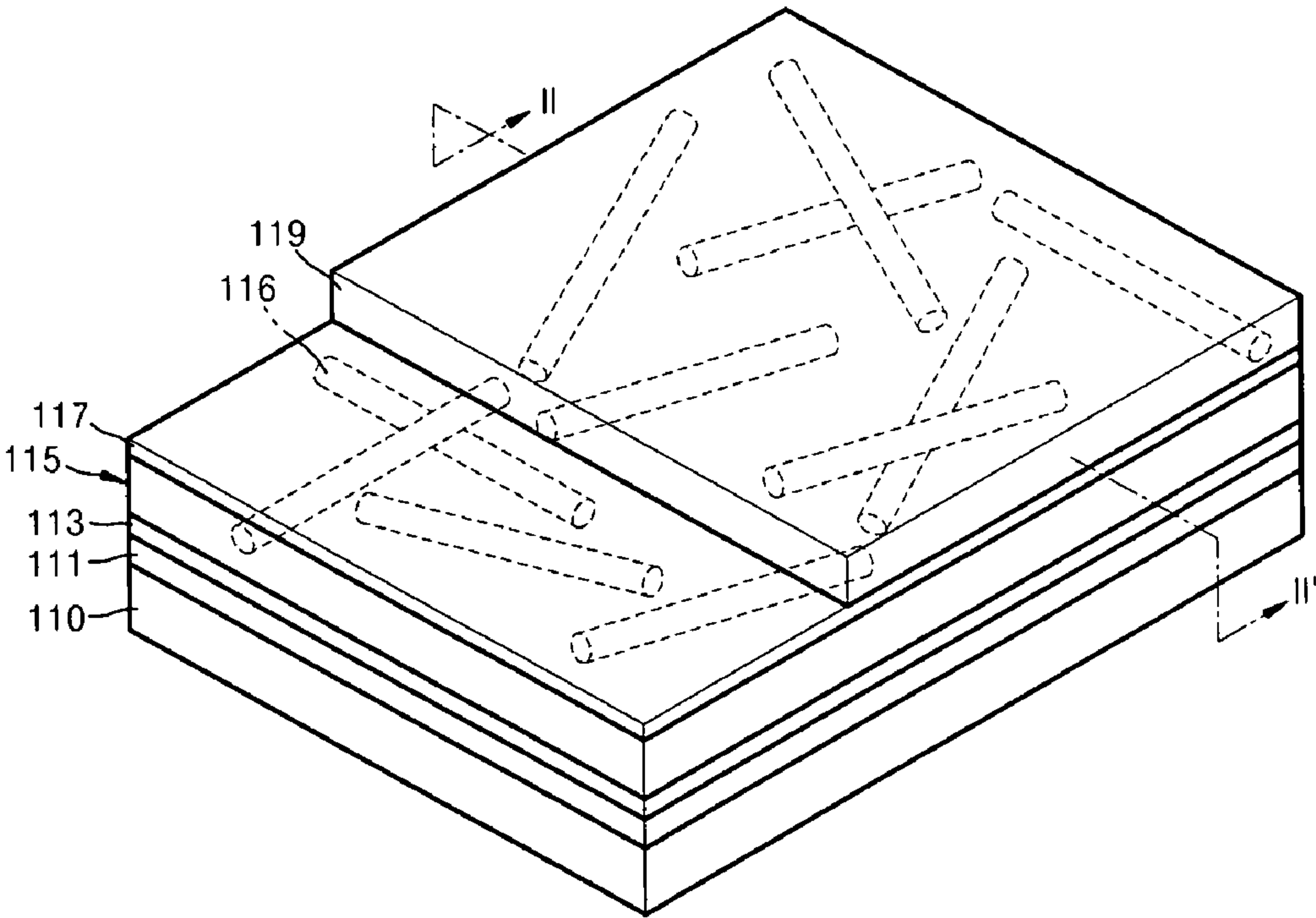


FIG. 2

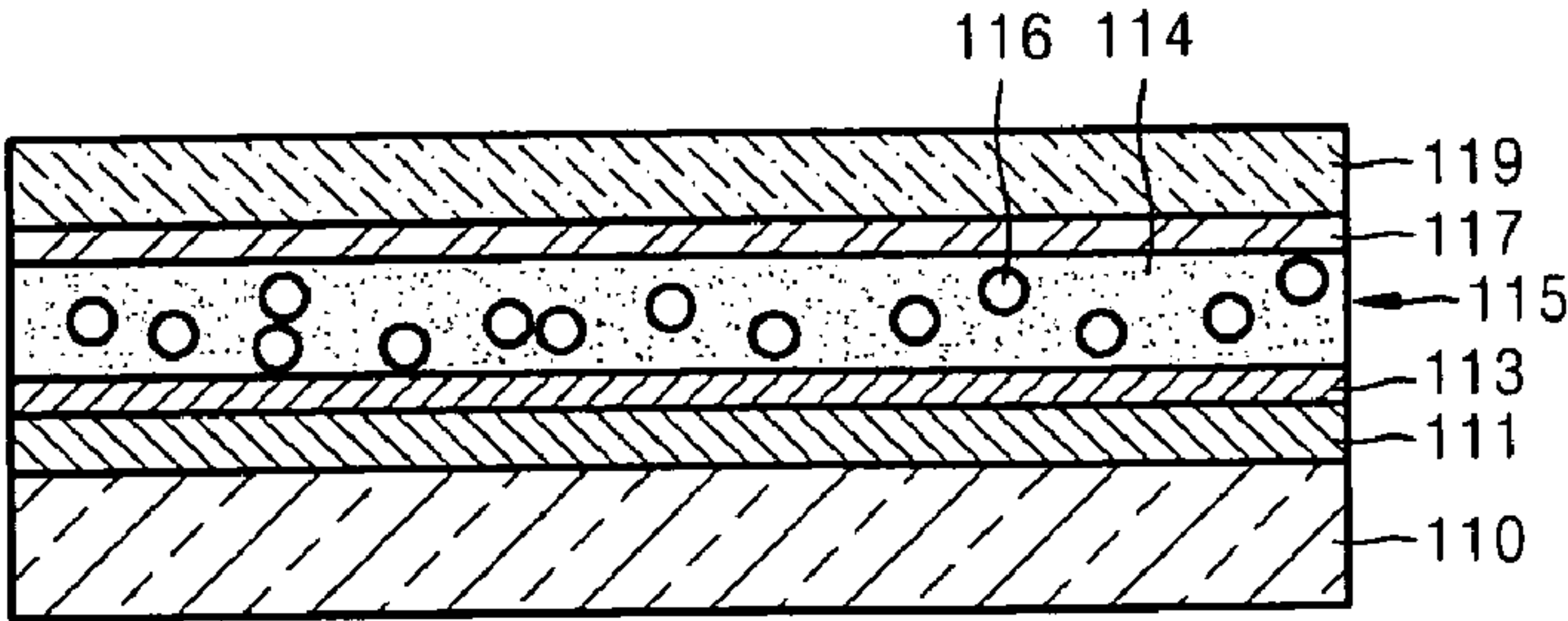


FIG. 3

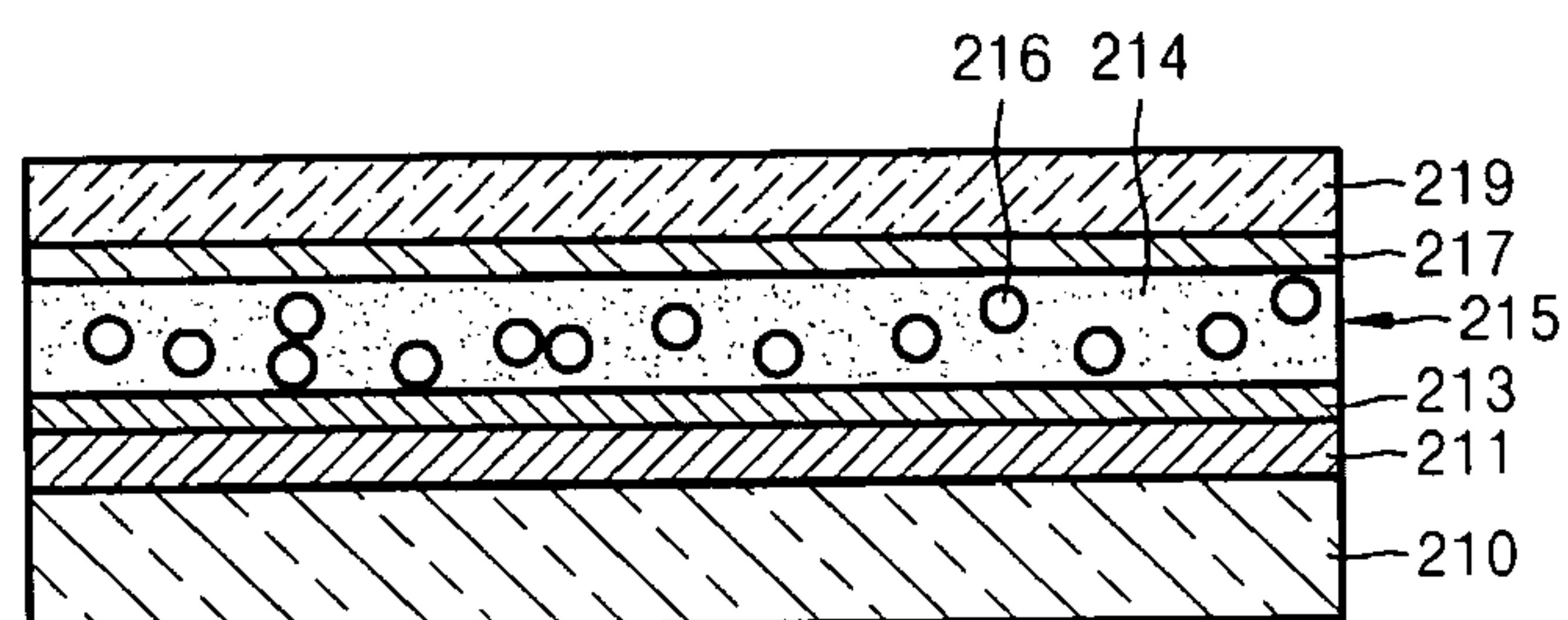


FIG. 4

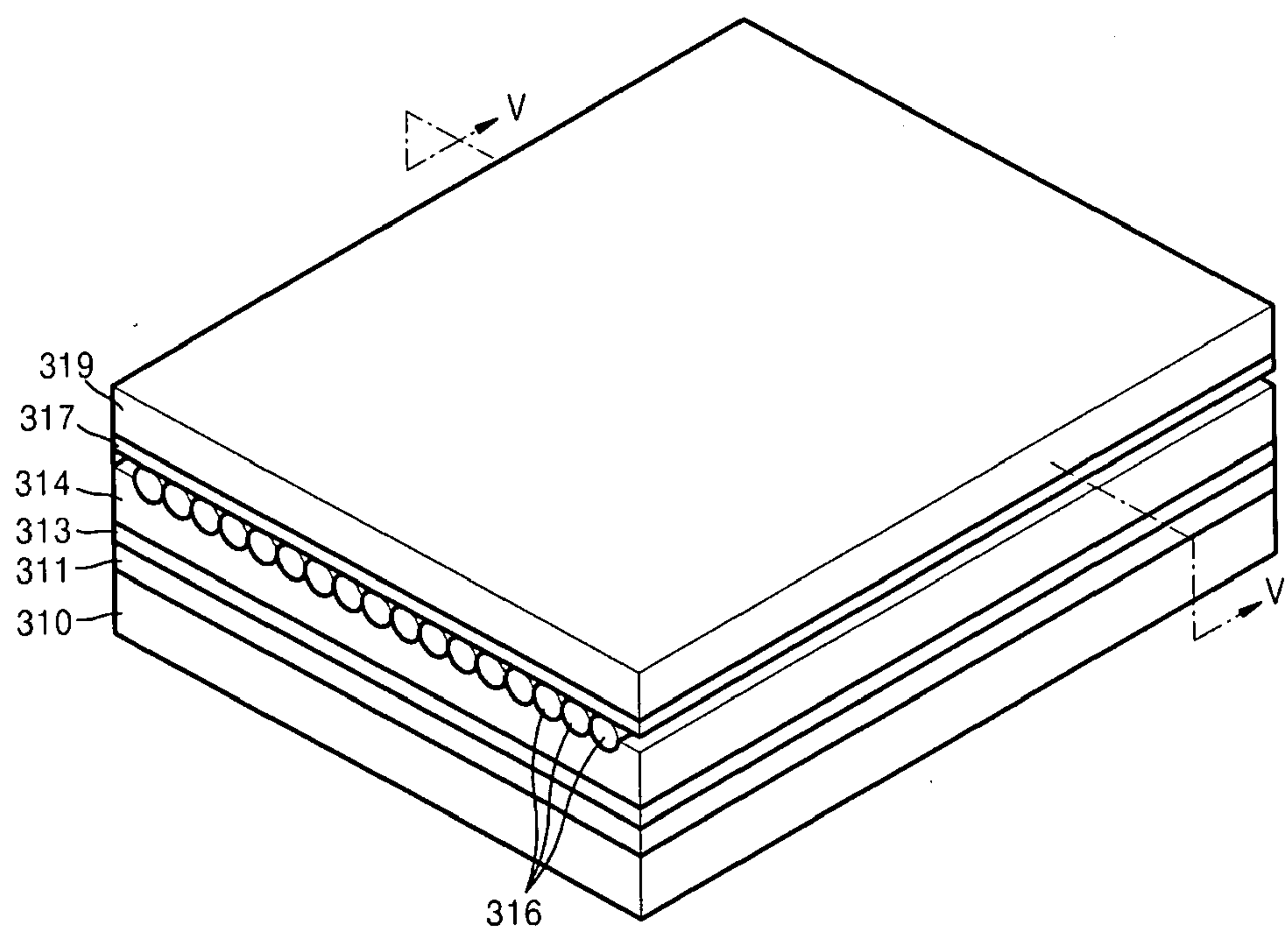


FIG. 5

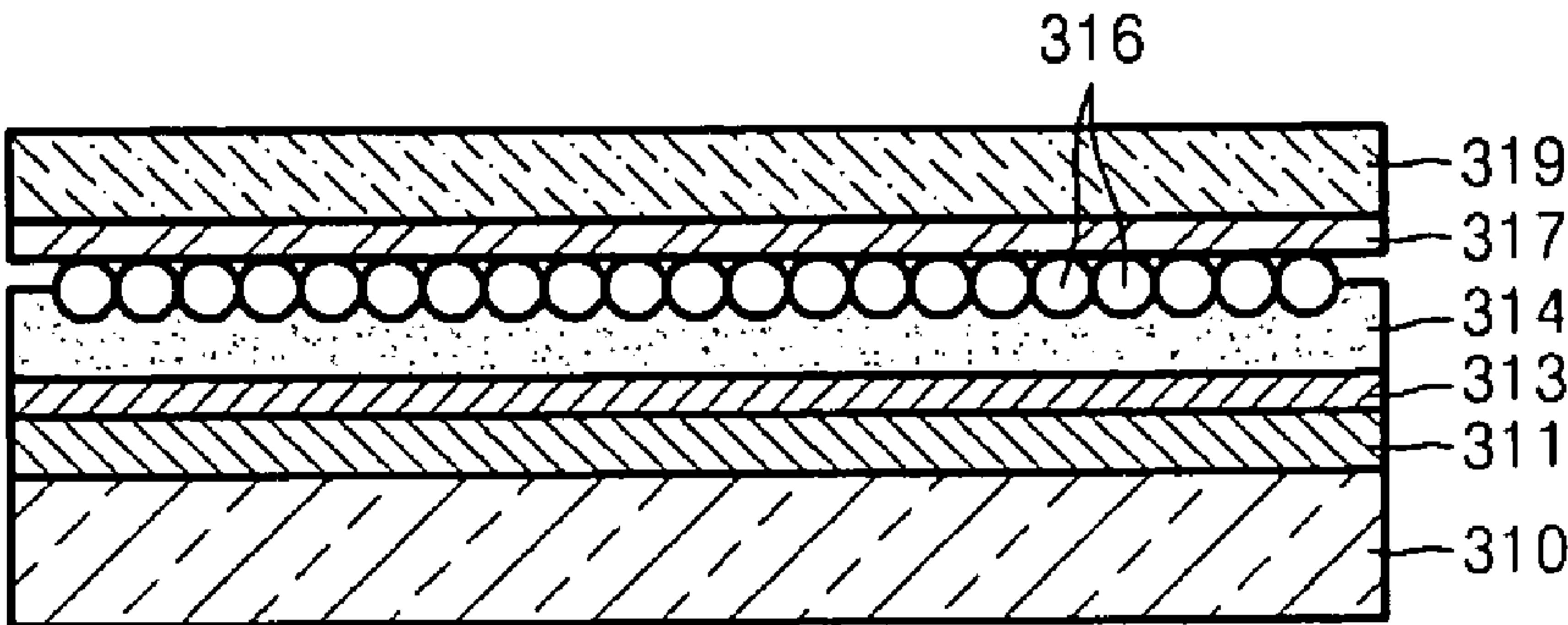


FIG. 6

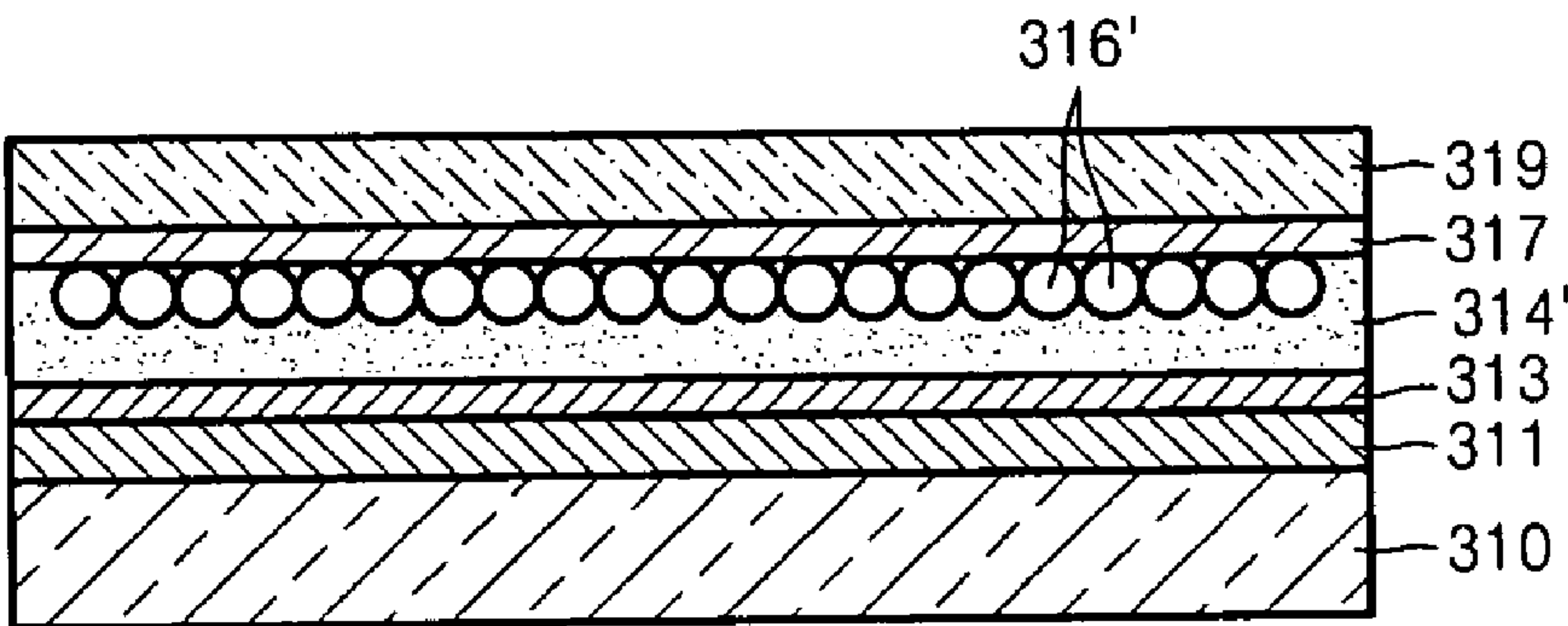


FIG. 7

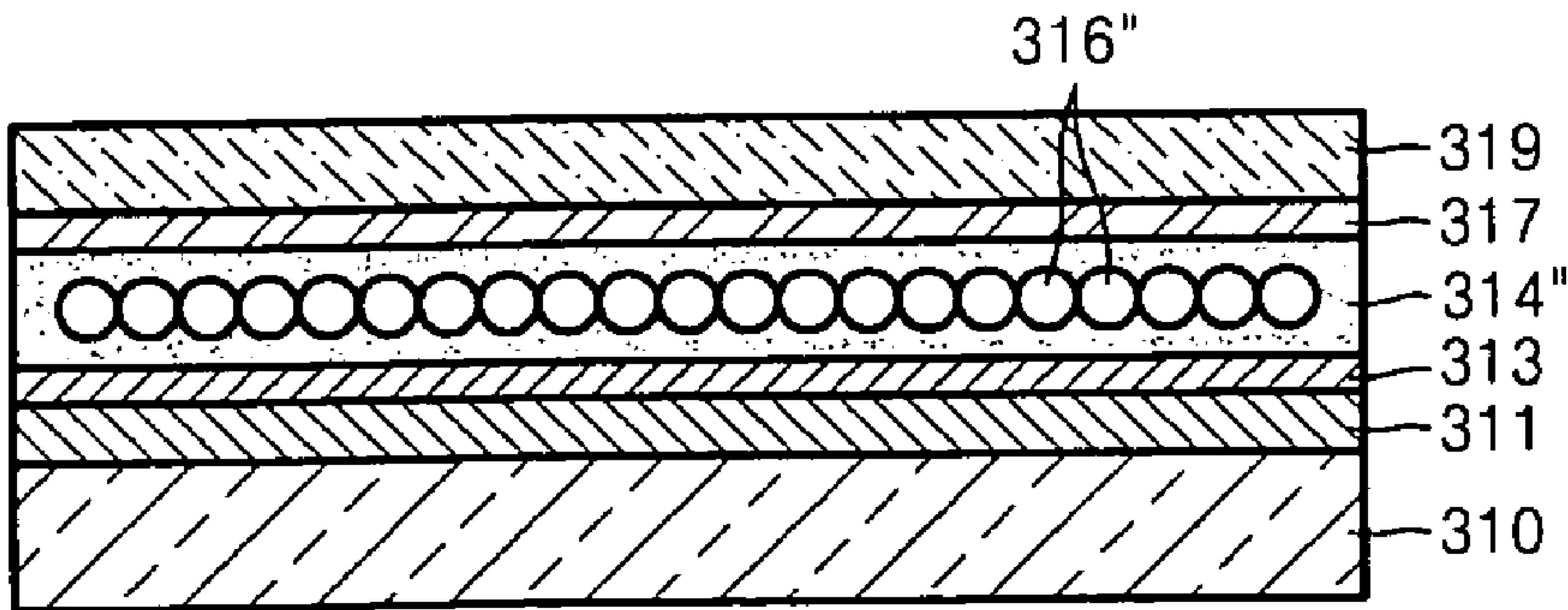


FIG. 8

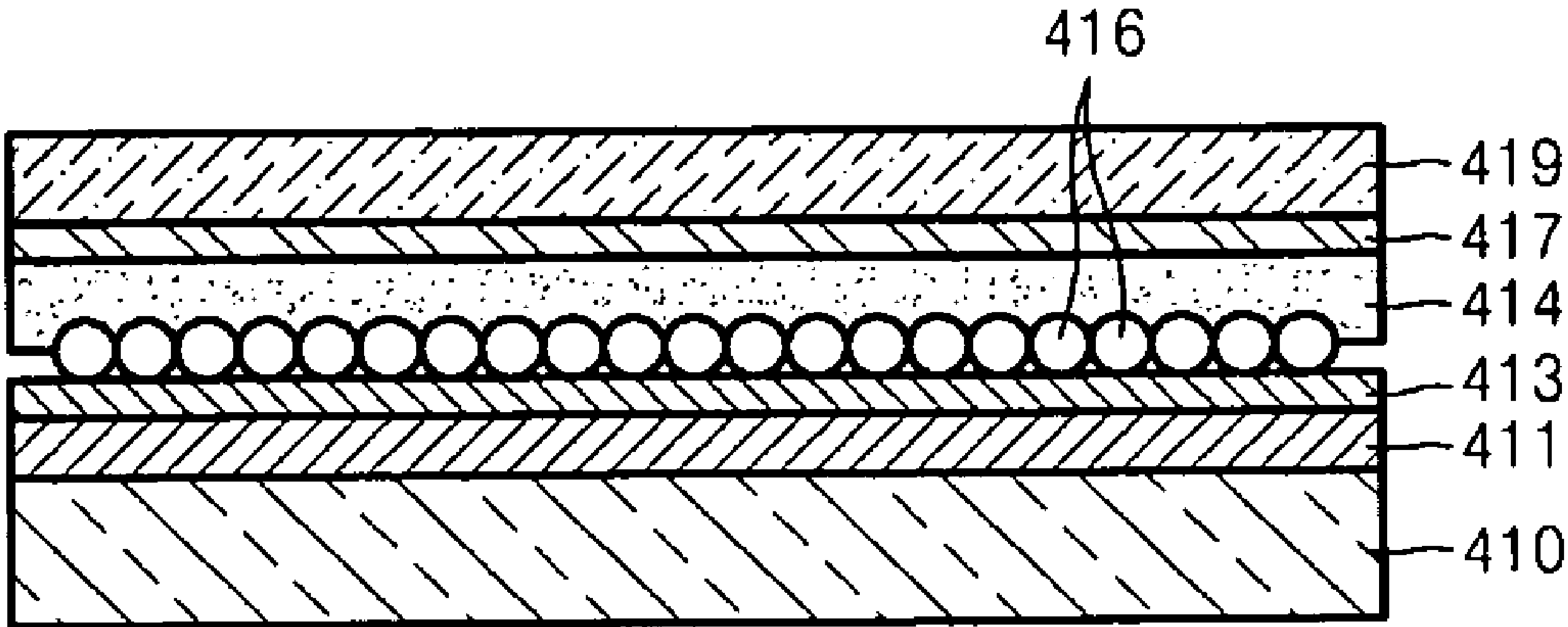


FIG. 9

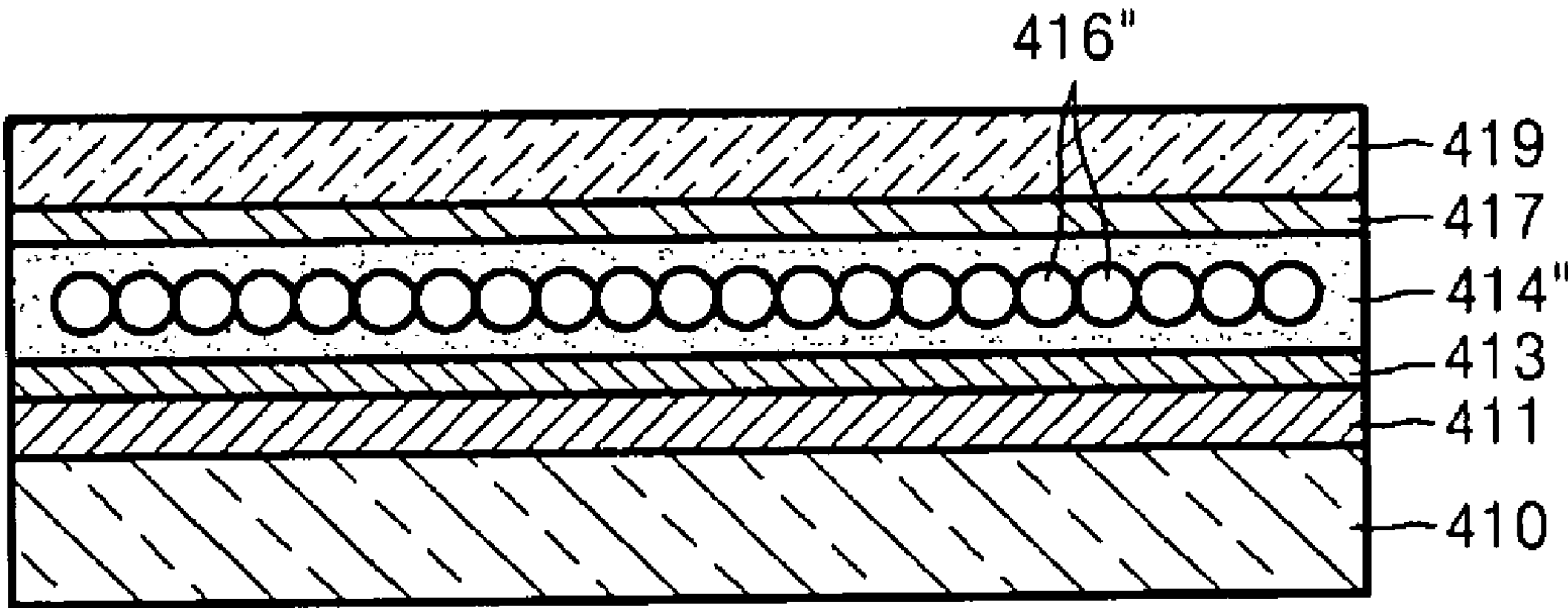


FIG. 10

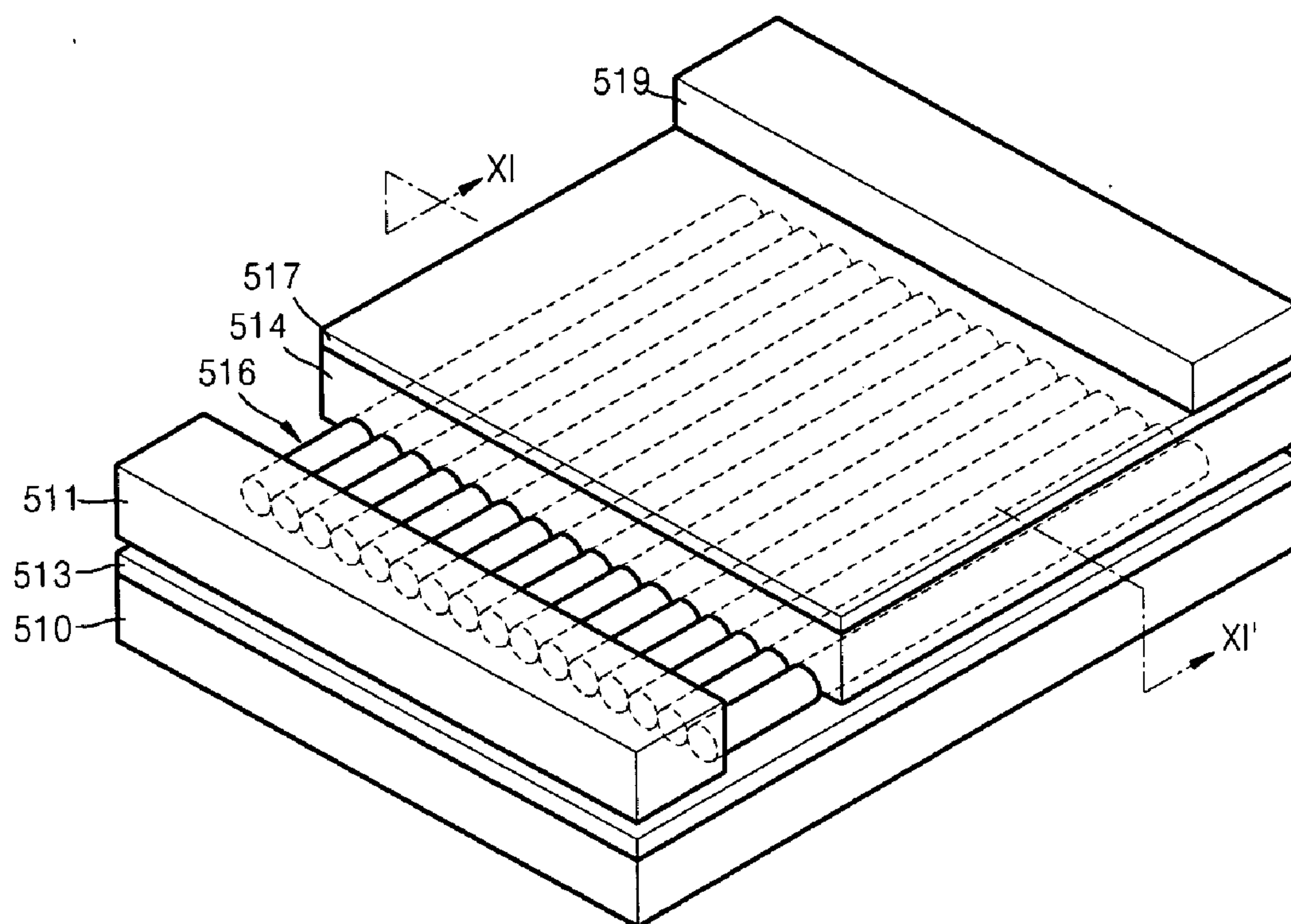
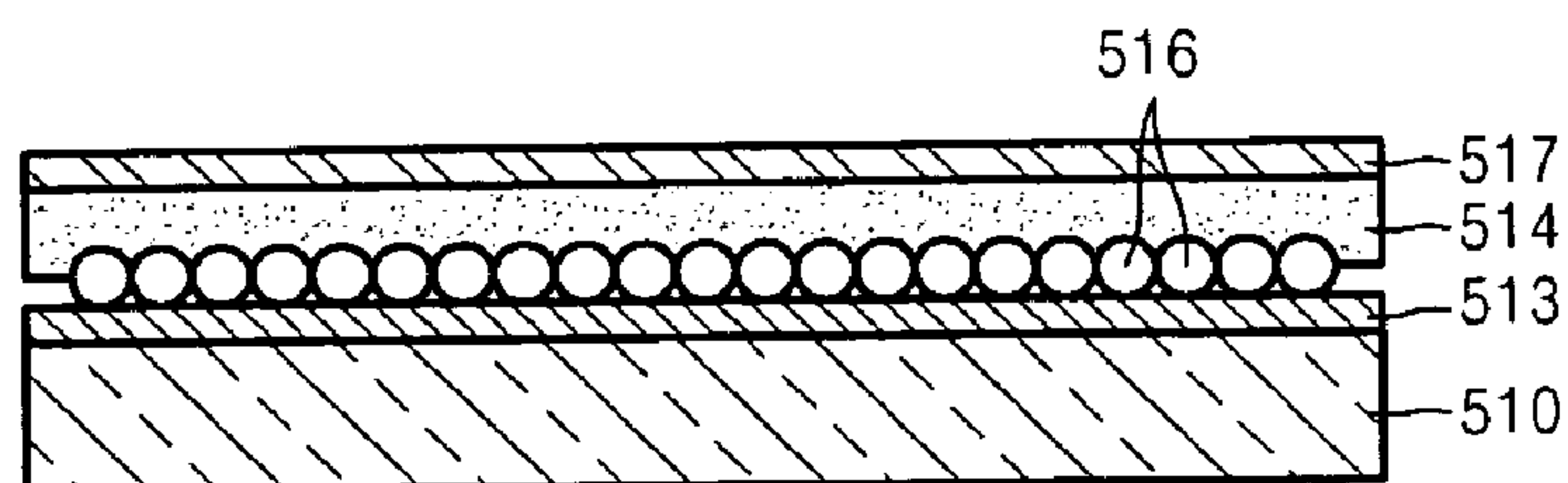


FIG. 11



SOLAR CELL HAVING ORGANIC NANOWIRES

CROSS-REFERENCE TO RELATED APPLICATION

[0001] This application claims priority under 35 U.S.C. §119 to Korean Patent Application No. 10-2009-0098412, filed on Oct. 15, 2009 with the Korean Intellectual Property Office, the entire disclosure of which is incorporated herein by reference.

BACKGROUND

[0002] 1. Field

[0003] The present disclosure relates to solar cells, including solar cells with organic nanowires.

[0004] 2. Description of the Related Art

[0005] Conventional silicon (Si) solar cells involve relatively high material costs, relatively expensive process equipment, and relatively high process costs. As a result, it has been difficult to reduce the manufacturing costs of conventional silicon solar cells. Also, it is relatively difficult to manufacture solar cells having larger areas, and substrates that may be used in manufacturing solar cells are rather limited. Organic solar cells may be conventionally formed by blending an n-type material formed of an inorganic material (e.g., fluorine) and a p-type material formed of an organic material. However, organic solar cells have a relatively low efficiency as a result of blending inorganic materials and organic materials. Thus, an additional annealing process is conventionally needed to manufacture organic solar cells.

SUMMARY

[0006] Example embodiments relate to solar cells including organic nanowires. A solar cell according to example embodiments may include a first electrode and a second electrode spaced apart from each other; and a photoelectric conversion layer between the first and second electrodes and configured to form p-n junctions, wherein the photoelectric conversion layer includes a p-type material and an n-type material, the p-type material including an organic material, and the n-type material including organic nanowires.

[0007] The n-type material may include perylene tetracarboxylic diimide (PTCDI) or a derivative thereof. The p-type material may include polythiophene (P3HT) or poly(phenylenevinylene) (PPV). The first and second electrodes may be a transparent electrode and a metal electrode, respectively.

[0008] The first and second electrodes may be a p-type electrode and an n-type electrode, respectively. In such a case, the solar cell may further include a hole transporting layer between the first electrode and the photoelectric conversion layer, and an electron transporting layer between the second electrode and the photoelectric conversion layer.

[0009] Alternatively, the first and second electrodes may be an n-type electrode and a p-type electrode, respectively. In such a case, the solar cell may further include a hole blocking layer between the first electrode and the photoelectric conversion layer, and a hole transporting layer between the second electrode and the photoelectric conversion layer.

[0010] Another solar cell according to example embodiments may include a first electrode and a second electrode spaced apart from each other; a p-type material layer including an organic material between the first and second electrodes; and an n-type material layer including aligned organic

nanowires between the first and second electrodes, the n-type material layer forming p-n junctions with the p-type material layer. The first and second electrodes may be parallel to the organic nanowires and arranged under and on the organic nanowires, respectively. Alternatively, the first and second electrodes may be perpendicular to the organic nanowires and disposed on end portions of the organic nanowires.

[0011] Another solar cell according to example embodiments may include a first electrode and a second electrode spaced apart from each other; and a plurality of photoelectric conversion layers between the first and second electrodes and configured to form p-n junctions, wherein each of the plurality of photoelectric conversion layers includes an n-type material and a p-type material, the n-type material including aligned organic nanowires, and the p-type material surrounding the aligned organic nanowires.

BRIEF DESCRIPTION OF THE DRAWINGS

[0012] The above and/or other aspects of example embodiments may become more apparent and readily appreciated when the following description is taken in conjunction with the accompanying drawings of which:

[0013] FIG. 1 is a perspective view illustrating a solar cell according to example embodiments;

[0014] FIG. 2 is a cross-sectional view of the solar cell of FIG. 1 along line II-II';

[0015] FIG. 3 is a cross-sectional view illustrating another solar cell according to example embodiments;

[0016] FIG. 4 is a perspective view illustrating another solar cell according to example embodiments;

[0017] FIG. 5 is a cross-sectional view illustrating the solar cell of FIG. 4 along line V-V';

[0018] FIG. 6 is a cross-sectional view illustrating a variation of the solar cell of FIG. 5;

[0019] FIG. 7 is a cross-sectional view illustrating another variation of the solar cell of FIG. 5;

[0020] FIG. 8 is a cross-sectional view illustrating another solar cell according to example embodiments;

[0021] FIG. 9 is a cross-sectional view illustrating a variation of the solar cell of FIG. 8;

[0022] FIG. 10 is a perspective view illustrating another solar cell according to example embodiments;

[0023] FIG. 11 is a cross-sectional view illustrating the solar cell of FIG. 10 along line XI-XI'; and

[0024] FIG. 12 is a plan view illustrating another solar cell according to example embodiments.

DETAILED DESCRIPTION

[0025] It will be understood that when an element or layer is referred to as being "on," "connected to," "coupled to," or "covering" another element or layer, it may be directly on, connected to, coupled to, or covering the other element or layer or intervening elements or layers may be present. In contrast, when an element is referred to as being "directly on," "directly connected to," or "directly coupled to" another element or layer, there are no intervening elements or layers present. Like numbers refer to like elements throughout the specification. As used herein, the term "and/or" includes any and all combinations of one or more of the associated listed items.

[0026] It will be understood that, although the terms first, second, third, etc. may be used herein to describe various elements, components, regions, layers, and/or sections, these

elements, components, regions, layers, and/or sections should not be limited by these terms. These terms are only used to distinguish one element, component, region, layer, or section from another element, component, region, layer, or section. Thus, a first element, component, region, layer, or section discussed below could be termed a second element, component, region, layer, or section without departing from the teachings of example embodiments.

[0027] Spatially relative terms, e.g., “beneath,” “below,” “lower,” “above,” “upper,” and the like, may be used herein for ease of description to describe one element or feature’s relationship to another element(s) or feature(s) as illustrated in the figures. It will be understood that the spatially relative terms are intended to encompass different orientations of the device in use or operation in addition to the orientation depicted in the figures. For example, if the device in the figures is turned over, elements described as “below” or “beneath” other elements or features would then be oriented “above” the other elements or features. Thus, the term “below” may encompass both an orientation of above and below. The device may be otherwise oriented (rotated 90 degrees or at other orientations) and the spatially relative descriptors used herein interpreted accordingly.

[0028] The terminology used herein is for the purpose of describing various embodiments only and is not intended to be limiting of example embodiments. As used herein, the singular forms “a,” “an,” and “the” are intended to include the plural forms as well, unless the context clearly indicates otherwise. It will be further understood that the terms, “comprises,” “comprising,” “includes,” and/or “including,” if used herein, specify the presence of stated features, integers, steps, operations, elements, and/or components, but do not preclude the presence or addition of one or more other features, integers, steps, operations, elements, components, and/or groups thereof.

[0029] Example embodiments are described herein with reference to cross-sectional illustrations that are schematic illustrations of idealized embodiments (and intermediate structures) of example embodiments. As such, variations from the shapes of the illustrations as a result, for example, of manufacturing techniques and/or tolerances, are to be expected. Thus, example embodiments should not be construed as limited to the shapes of regions illustrated herein but are to include deviations in shapes that result, for example, from manufacturing.

[0030] Unless otherwise defined, all terms (including technical and scientific terms) used herein have the same meaning as commonly understood by one of ordinary skill in the art. It will be further understood that terms, including those defined in commonly used dictionaries, should be interpreted as having a meaning that is consistent with their meaning in the context of the relevant art and will not be interpreted in an idealized or overly formal sense unless expressly so defined herein.

[0031] FIG. 1 is a perspective view illustrating a solar cell according to example embodiments. FIG. 2 is a cross-sectional view of the solar cell of FIG. 1 along line II-II'. Referring to FIGS. 1 and 2, the solar cell may include a first electrode 111 and a second electrode 119 that are separated apart from each other. A photoelectric conversion layer 115 may be disposed between the first electrode 111 and the second electrode 119 and configured to form p-n junctions. The first electrode 111 may be a p-type electrode and may be formed of, for example, a transparent conductive material

(e.g., indium tin oxide (ITO)), although example embodiments are not limited thereto. The first electrode 111 may be formed on a substrate 110. The substrate 110 may be a transparent substrate formed of, for example, glass or plastic. However, the substrate 110 is not limited thereto and may be formed of other various materials.

[0032] A hole transporting layer (HTL) 113 may be further formed on the first electrode 111. Holes generated by the photoelectric conversion layer 115 may move to the first electrode 111, which may be a p-type electrode, with relative ease as a result of the HTL 113. The HTL 113 may be formed of, for example, poly(3,4-ethylene dioxythiophene):poly(styrene sulfate) (PEDOT:PSS), although example embodiments are not limited thereto.

[0033] The photoelectric conversion layer 115, which generates holes and electrons by absorbing light, may be formed on the HTL 113. The photoelectric conversion layer 115 may be formed of a p-type material 114 including an organic material and an n-type material 116 including organic nanowires. The organic nanowires may refer to organic materials shaped as nanowires. The p-type material 114 may be formed of, for example, polythiophene (P3HT), poly(phenylenevinylene) (PPV), or other various materials. Also, the n-type material 116 may include nanowires formed of, for example, perylene tetracarboxylic diimide (PTCDI) or any of the derivatives thereof, although example embodiments are not limited thereto. For example, the photoelectric conversion layer 115 may be formed of a composite in which the n-type material 116 including N,N-bis(2-phenylethyl)-peryene-3,4:9,10-tetracarboxylic diimide (BPE-PTCDI) nanowires are dispersed in the p-type material 114 including P3HT. The BPE-PTCDI nanowires may be randomly dispersed in the P3HT.

[0034] The photoelectric conversion layer 115 formed of a composite of BPE-PTCDI nanowires and P3HT may be formed in the following manner. The BPE-PTCDI may be mixed with P3HT in an o-dichlorobenzene (ODCB) solution. The mixed solution may be heated at a predetermined temperature, for example, 160° C., and gradually cooled. Accordingly, BPE-PTCDI nanowires may be formed by self-assembly. The BPE-PTCDI nanowires may have a diameter of about several tens of nm and a length of about several tens of μm . The mixture solution containing the BPE-PTCDI nanowires and the P3HT may be coated on the HTL 113, thereby forming the photoelectric conversion layer 115 formed of a composite of BPE-PTCDI and P3HT. The coating of the mixture solution may be performed by spin coating, spin casting, or doctor blading, although other suitable techniques may also be used.

[0035] An electron transporting layer (ETL) 117 may be further formed on the photoelectric conversion layer 115. Electrons generated by the photoelectric conversion layer 115 may move to the second electrode 119, which may be an n-type electrode, with relative ease as a result of the ETL 117. The ETL 117 may be formed of, for example, LiF or other various materials. The second electrode 119 is formed on the ETL 117. The second electrode 119 may be an n-type electrode, and may be formed of, for example, a metal (e.g., Al). However, the second electrode 119 is not limited thereto.

[0036] As described above, the photoelectric conversion layer 115 may be formed of a composite of the p-type material 114 formed of an organic material and the n-type material 116 formed of organic nanowires having desirable crystalline characteristics. Accordingly, charge movement characteris-

tics and charge collecting characteristics may be improved, and the recombination of holes and electrons may be reduced, thereby increasing the efficiency of the solar cell. In addition, by manufacturing the solar cell using an organic material, manufacturing costs may be reduced, and also, relatively large-sized solar cells or flexible solar cells may be implemented.

[0037] FIG. 3 is a cross-sectional view illustrating another solar cell according to example embodiments. It should be noted that the description of features corresponding to previously-discussed elements will not be repeated below for purposes of brevity. Rather, the descriptions hereinafter will focus on differences from the previous example(s).

[0038] Referring to FIG. 3, a first electrode 211 may be formed on a substrate 210. The first electrode 211 may be an n-type electrode formed of a transparent conductive material, e.g., fluorine-doped tin oxide (FTO). However, the first electrode 211 is not limited thereto. A hole blocking layer (HBL) 213 may be formed on the first electrode 211. The HBL 213 blocks holes generated by a photoelectric conversion layer 215 (which will be described later) from moving to the first electrodes 211, which may be an n-type electrode. The HBL 213 may be formed of, for example, TiO_2 or other various materials.

[0039] The photoelectric conversion layer 215 may be formed on the HBL 213. As described above, the photoelectric conversion layer 215 may be formed of a p-type material 214 including an organic material and an n-type material 216 including organic nanowires. The p-type material 214 may include, for example, P3HT or PPV. Also, the n-type material 216 may include, for example, nanowires formed of PTCDI or any of the derivatives thereof. However, the p-type material 214 and the n-type material 216 are not limited thereto.

[0040] An HTL 217 may be further formed on the photoelectric conversion layer 215. The HTL 217 may be formed of, for example, PEDOT:PSS or other various materials. A second electrode 219 may be formed on the HTL 217. The second electrode 219 may be a p-type electrode formed of a metal (e.g., Au). However, the second electrode 219 is not limited thereto.

[0041] FIG. 4 is a perspective view illustrating another solar cell according to example embodiments. FIG. 5 is a cross-sectional view illustrating the solar cell of FIG. 4 along line V-V'. Referring to FIGS. 4 and 5, the solar cell may include a first electrode 311 and a second electrode 319 that are separated apart from each other and a p-type material layer 314 and an n-type material layer 316 that are disposed between the first and second electrodes 311 and 319. The first electrode 311 may be a p-type electrode formed of a transparent conductive material (e.g., ITO). However, the first electrode 311 is not limited thereto. The first electrode 311 may be formed on a substrate 310. The substrate 310 may be a transparent substrate formed of, for example, glass or plastic. However, the substrate 310 is not limited thereto and may be formed of other various materials.

[0042] An HTL 313 may be formed on the first electrode 311. The HTL 313 may be formed of, for example, PEDOT:PSS or other various materials. The p-type material layer 314 formed of an organic material may be formed on the HTL 313. The p-type material layer 314 may be formed of, for example, P3HT, PPV, or other various materials. The n-type material layer 316 may be formed on the p-type material layer 314. The n-type material layer 316 and the p-type material layer 314 may form p-n junctions. The n-type material layer

316 may be formed of aligned organic nanowires. The organic nanowires may be aligned so as to be parallel to the first and second electrodes 311 and 319. Referring to FIG. 5, the organic nanowires are illustrated as being formed so as to contact one another. However, it should be understood that example embodiments are not limited thereto. For instance, the organic nanowires may be separated from one another by predetermined distances. The n-type material layer 316 may include, for example, nanowires formed of PTCDI or derivatives thereof (e.g., BPE-PIDCI). However, the n-type material layer 316 is not limited thereto.

[0043] The n-type material layer 316 formed of, for example, aligned BPE-PTCDI nanowires may be formed in the following manner. BPE-PTCDI may be mixed in an ODCB solution. The mixture solution may be heated at a predetermined temperature (e.g., 160°C .) and gradually cooled. Accordingly, BPE-PTCDI nanowires may be formed by self-assembly. The BPE-PTCDI nanowires may have a diameter of about several tens of nm and a length of about several tens of μm . The BPE-PTCDI nanowires may be aligned using a filtration and transfer (FAT) process. The n-type material layer 316 may be formed by transferring the BPE-PTCDI nanowires onto the p-type material layer 314.

[0044] An electron transporting layer (ETL) 317 may be further formed on the n-type material layer 316. The ETL 317 may be formed of, for example, LiF or other various materials. The second electrode 319 is formed on the ETL 317. The second electrode 319 may be an n-type electrode and may be formed of, for example, a metal (e.g., Al). However, the second electrode 319 is not limited thereto.

[0045] As described above, the n-type material layer 316 formed of aligned organic nanowires may be formed on the p-type material layer 314 formed of an organic material. Accordingly, charges generated by light absorption may move with relative ease to the first and second electrodes 311 and 319 along the aligned organic nanowires separated at predetermined intervals, thereby further increasing the efficiency of the solar cell. In addition, because the solar cell is manufactured by using an organic material, the manufacturing costs thereof may be reduced and relatively large-sized solar cells or flexible solar cells may be implemented.

[0046] FIG. 6 is a cross-sectional view illustrating a variation of the solar cell of FIG. 5. Referring to FIG. 6, a p-type material layer 314' that is formed of an organic material and on an HTL 313 may be formed so as to cover an n-type material layer 316' that is formed of aligned organic nanowires and on a lower surface of an ETL 317. The p-type material layer 314' may be formed so as to contact an upper surface of the HTL 313 and the lower surface of the ETL 317.

[0047] FIG. 7 is a cross-sectional view illustrating another variation of the solar cell of FIG. 5. Referring to FIG. 7, an n-type material layer 316'' that is formed of aligned organic nanowires may be formed within a p-type material layer 314'' that is formed of an organic material and on an HTL 313. The p-type material layer 314'' is formed between the HTL 313 and an ETL 317, and the n-type material layer 316'' may be formed so as to be buried within the p-type material layer 314''.

[0048] FIG. 8 is a cross-sectional view illustrating another solar cell according to example embodiments. It should be noted that the description of features corresponding to previously-discussed elements will not be repeated below for purposes of brevity. Rather, the descriptions hereinafter will focus on differences from the previous example(s).

[0049] Referring to FIG. 8, a first electrode **411** may be formed on a substrate **410**. The first electrode **411** may be an n-type electrode formed of a transparent conductive material (e.g., FTO). However, the first electrode **411** is not limited thereto. A hole blocking layer (HBL) **413** may be formed on the first electrode **411**. The HBL **413** may be formed of, for example, TiO_2 or other various materials.

[0050] An n-type material layer **416** is formed on the HBL **413**. As described above, the n-type material layer **416** may be formed of aligned organic nanowires. The aligned organic nanowires may be aligned so as to be parallel to the first electrode **411** and a second electrode **419**. The n-type material layer **416** may include, for example, nanowires formed of PTCDI or any suitable derivatives thereof. However, the n-type material layer **416** is not limited thereto.

[0051] A p-type material layer **414** is formed on the n-type material layer **416**. The p-type material layer **414** and the n-type material layer **416** may form p-n junctions. The p-type material layer **414** may be formed of, for example, P3HT or PPV. Also, an HTL **417** may be further formed on the p-type material layer **414**. For example, the HTL **417** may be formed of PEDOT:PSS or other various materials. The second electrode **419** is formed on the HTL **417**. The second electrode **419** may be a p-type electrode and may be formed of a metal (e.g., Au). However, the second electrode **419** is not limited thereto. Also, as shown in FIG. 8, the p-type material layer **414** is illustrated as being formed so as to rest on the n-type material layer **416**. However, it should be understood that, alternatively, the p-type material layer **414** may be formed to conformally cover the n-type material layer **416**. For instance, the p-type material layer **414** may be formed so as to contact a lower surface of the HTL **417** and an upper surface of the HBL **413**.

[0052] FIG. 9 is a cross-sectional view illustrating a variation of the solar cell of FIG. 8. Referring to FIG. 9, an n-type material layer **416'** formed of aligned organic nanowires may be buried within a p-type material layer **414'** formed of an organic material. The p-type material layer **414'** may be disposed between an HTL **417** and an HBL **413**.

[0053] FIG. 10 is a perspective view illustrating another solar cell according to example embodiments. FIG. 11 is a cross-sectional view illustrating the solar cell of FIG. 10 along line XI-XI'. Referring to FIGS. 10 and 11, the solar cell may include an n-type material layer **516** including aligned organic nanowires formed on a substrate **510**, a p-type material layer **514** formed on the n-type material layer **516**, and first and second electrodes **511** and **519** that are respectively formed at two ends of the n-type material layer **516** in a direction perpendicular to a direction in which the aligned organic nanowires extend. An ETL **513** may be further formed on the substrate **510**. The substrate **510** may be a transparent substrate and may be formed of glass, plastic, or other suitable materials. However, the substrate **510** is not limited thereto and may be formed of other various materials. The ETL **513** may be formed of, for example, LiF or other various materials.

[0054] The n-type material layer **516** formed of aligned organic nanowires may be formed on the ETL **513**. The organic nanowires may be aligned so as to be parallel to a surface of the substrate **510**. In FIGS. 10 and 11, the organic nanowires of the n-type material layer **516** are illustrated as contacting one another. However, it should be understood that, alternatively, the organic nanowires may be separated from each other at predetermined intervals. The n-type mate-

rial layer **516** may include nanowires formed of, for example, PTCDI or any suitable derivatives thereof (e.g., BPE-PTCDI). However, the n-type material layer **516** is not limited thereto.

[0055] The first electrode **511** may be formed on the ETL **513** so as to cover a first end portion of the aligned organic nanowires. The first electrode **511** may be formed in a direction perpendicular to a direction in which the aligned organic nanowires extend. The first electrode **511** may be an n-type electrode and may be formed of a transparent conductive material (e.g., FTO). However, the first electrode **511** is not limited thereto. Also, the p-type material layer **514** formed of an organic material may be formed on the n-type material layer **516**. The p-type material layer **514** may be separated from the first electrode **511**. Alternatively, the p-type material layer **514** may be formed on the ETL **513** so as to completely cover the n-type material layer **516** and/or may be formed so as to bury the n-type material layer **516**. Also, although not shown in the drawing, an insulation layer may be further formed between the p-type material layer **514** and the first electrode **511**, which may be an n-type electrode.

[0056] An HTL **517** may be further formed on the p-type material layer **514**. The HTL **517** may be formed of, for example, PEDOT:PSS or other various materials. The second electrode **519** is formed on the HTL **517**. The second electrode **519** may be disposed on a second end portion of the aligned organic nanowires of the n-type material layer **516**. The second electrode **519** may be disposed in a direction perpendicular to a direction in which the aligned organic nanowires extend. The second electrode **519** may be a p-type electrode and may be formed of a metal (e.g., Au). However, the second electrode **519** is not limited thereto. As described above, the first and second electrodes **511** and **519** may be formed on two ends portions of the aligned organic nanowires of the n-type material layer **516** in a direction perpendicular to a direction in which the aligned organic nanowires extend.

[0057] FIG. 12 is a plan view illustrating another solar cell according to example embodiments. Referring to FIG. 12, the solar cell may include a first electrode **611** and a second electrode **619** that are separated apart from each other, and a plurality of photoelectric conversion layers **615** that are formed between the first and second electrodes **611** and **619**. The first and second electrodes **611** and **619** and the plurality of the photoelectric conversion layers **615** may be formed on a substrate **600**. The substrate **600** may be a transparent substrate and may be formed of glass, plastic, or other suitable materials. However, the substrate **600** is not limited thereto.

[0058] The photoelectric conversion layers **615** may be formed of an n-type material **616** and a p-type material **614** surrounding the n-type material **616**. The p-type material **614** may be formed of, for example, P3HT, PPV, or other various materials. The n-type material **616** may include, for example, nanowires formed of PTCDI or suitable derivatives thereof. However, the n-type material **616** is not limited thereto. The p-type material **614** may be formed so as to cover the n-type material **616**. For instance, the p-type material **614** may be formed on the n-type material **616** or may be formed so as to bury the n-type material **616** therein. Organic nanowires of the n-type material **616** may be aligned in a direction perpendicular to the first and second electrodes **611** and **619**. For example, the first and second electrodes **611** and **619** may be aligned in a direction perpendicular to a direction in which the organic nanowires extend and disposed on two end portions of the organic nanowires of the n-type material **616**.

[0059] The first and second electrodes **611** and **619** may be a p-type electrode and an n-type electrode, respectively. An HTL **613** may be further disposed between the first electrode **611** and the photoelectric conversion layers **615**. Also, an ETL **617** may be disposed between the second electrode **619** and the photoelectric conversion layers **615**. Alternatively, the first and second electrodes **611** and **619** may be an n-type electrode and a p-type electrode, respectively. In such a case, an ETL (not shown) may be disposed between the first electrode **611** and the photoelectric conversion layers **615**, and an HTL (not shown) may be disposed between the second electrode **619** and the photoelectric conversion layers **615**. Referring to FIG. 12, the plurality of photoelectric conversion layers **615** may be arranged on a transparent substrate **600**, thereby resulting in the manufacture of a relatively large-sized solar cell. In addition, a photo current generated by the solar cell may also be increased.

[0060] As described above according to example embodiments, the photoelectric conversion layers of a solar cell may be formed using a p-type material including an organic material and an n-type material including organic nanowires having desired crystalline characteristics, thereby improving the charge mobility and charge collecting characteristics, reducing recombination of holes and electrons, and increasing the efficiency of the solar cell. In addition, because the solar cell is manufactured using an organic material, the manufacturing costs thereof may be reduced, and relatively large-sized solar cells or flexible solar cells may be manufactured.

[0061] While example embodiments have been disclosed herein, it should be understood that other variations may be possible. Such variations are not to be regarded as a departure from the spirit and scope of example embodiments of the present application, and all such modifications as would be obvious to one skilled in the art are intended to be included within the scope of the following claims.

What is claimed is:

1. A solar cell comprising:
 - a first electrode and a second electrode spaced apart from each other; and
 - a photoelectric conversion layer between the first and second electrodes and configured to form p-n junctions, wherein the photoelectric conversion layer includes a p-type material and an n-type material, the p-type material including an organic material, and the n-type material including organic nanowires.
2. The solar cell of claim 1, wherein the n-type material includes perylene tetracarboxylic diimide (PTCDI) or a derivative thereof.
3. The solar cell of claim 1, wherein the p-type material includes polythiophene (P3HT) or poly(phenylenevinylene) (PPV).
4. The solar cell of claim 1, wherein the first and second electrodes are a transparent electrode and a metal electrode, respectively.
5. The solar cell of claim 1, wherein the first and second electrodes are a p-type electrode and an n-type electrode, respectively.
6. The solar cell of claim 5, further comprising:
 - a hole transporting layer between the first electrode and the photoelectric conversion layer; and
 - an electron transporting layer between the second electrode and the photoelectric conversion layer.

7. The solar cell of claim 1, wherein the first and second electrodes are an n-type electrode and a p-type electrode, respectively.

8. The solar cell of claim 7, further comprising:

- a hole blocking layer between the first electrode and the photoelectric conversion layer; and
- a hole transporting layer between the second electrode and the photoelectric conversion layer.

9. The solar cell of claim 1, wherein the organic nanowires of the photoelectric conversion layer are self-assembled from a mixture of the p-type material and the n-type material.

10. A solar cell comprising:

- a first electrode and a second electrode spaced apart from each other;
- a p-type material layer including an organic material between the first and second electrodes; and
- an n-type material layer including aligned organic nanowires between the first and second electrodes, the n-type material layer forming p-n junctions with the p-type material layer.

11. The solar cell of claim 10, wherein the n-type material layer includes perylene tetracarboxylic diimide (PTCDI) or a derivative thereof.

12. The solar cell of claim 10, wherein the p-type material includes polythiophene (P3HT) or poly(phenylenevinylene) (PPV).

13. The solar cell of claim 10, wherein the first and second electrodes are parallel to the organic nanowires and arranged under and on the organic nanowires, respectively.

14. The solar cell of claim 10, wherein the first and second electrodes are perpendicular to the organic nanowires and disposed on end portions of the organic nanowires.

15. The solar cell of claim 10, wherein the n-type material layer is formed on the p-type material layer.

16. The solar cell of claim 10, wherein the p-type material layer covers the n-type material layer.

17. The solar cell of claim 10, wherein the n-type material layer is buried within the p-type material layer.

18. The solar cell of claim 10, wherein the first and second electrodes are a transparent electrode and a metal electrode, respectively.

19. The solar cell of claim 10, wherein the first and second electrodes are a p-type electrode and an n-type electrode, respectively.

20. The solar cell of claim 19, further comprising:

- a hole transporting layer between the first electrode and the p-type material layer; and
- an electron transporting layer between the second electrode and the n-type material layer.

21. The solar cell of claim 10, wherein the first and second electrodes are an n-type electrode and a p-type electrode, respectively.

22. The solar cell of claim 21, further comprising:

- a hole blocking layer between the first electrode and the n-type material layer; and
- a hole transporting layer between the second electrode and the p-type material layer.

23. A solar cell comprising:

- a first electrode and a second electrode spaced apart from each other; and
- a plurality of photoelectric conversion layers between the first and second electrodes and configured to form p-n junctions,

wherein each of the plurality of photoelectric conversion layers includes an n-type material and a p-type material, the n-type material including aligned organic nanowires, and the p-type material surrounding the aligned organic nanowires.

24. The solar cell of claim **23**, wherein the first and second electrodes are perpendicular to the organic nanowires and arranged on end portions of the organic nanowires.

25. The solar cell of claim **23**, further comprising:
a hole transporting layer between the first electrode and the plurality of photoelectric conversion layers; and

an electron transporting layer between the second electrode and the plurality of photoelectric conversion layers.

26. The solar cell of claim **23**, further comprising:

a hole blocking layer between the first electrode and the plurality of photoelectric conversion layers; and

a hole transporting layer between the second electrode and the plurality of photoelectric conversion layers.

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